

L Number	Hits	Search Text	DB	Time stamp
-	5553	("257/296-313") or ("257/532")).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/04/29 23:23
-	37	((("257/296-313") or ("257/532")).CCLS.) and dielectric with (amorphous and crystal\$6)	USPAT	2001/04/29 21:50
-	17	((("257/296-313") or ("257/532")).CCLS.) and dielectric with amorphous with crystal\$6	USPAT	2001/04/29 22:04
-	891	dielectric and amorphous and crystal\$6	EPO; JPO; DERWENT; IBM TDB	2001/04/29 22:05
-	112	(dielectric and amorphous and crystal\$6) and capacitor	EPO; JPO; DERWENT; IBM TDB	2001/04/29 23:26
-	1	jp-62046508-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/04/29 22:33
-	0	62046508.URPN.	USPAT	2001/04/29 22:12
-	1	JP-62046508-\$.DID.	DERWENT	2001/04/29 22:12
-	2	jp-01315124-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/04/29 22:34
-	1	1989jp-0315124.ap,prai.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/04/29 22:44
-	3	5587870.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/04/29 22:52
-	2	5978207.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/04/29 22:55
-	0	((("257/296-313") or ("257/532")).CCLS.) and crystalline adj silicon adj nitride with silicon adj oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/04/29 22:56
-	0	crystalline adj silicon adj nitride and silicon adj oxide and capacitor	EPO; JPO; DERWENT; IBM TDB	2001/04/29 22:56
-	2	jp-05047597-\$.did.	EPO; JPO; DERWENT; IBM TDB	2001/04/29 23:20
-	2	jp-11121695-\$.did.	EPO; JPO; DERWENT; IBM TDB	2001/04/29 23:22
-	2	jp-2000252434-\$.did.	EPO; JPO; DERWENT; IBM TDB	2001/04/29 23:22
-	5553	("257/296-313") or ("257/532")).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/04/29 23:23

-	0	"JP 2000252434 A".DID. and dielectric with crystal\$6 and amorphous	USPAT	2001/04/29 23:24
-	17	((("257/296-313") or ("257/532")).CCLS.) and dielectric with crystal\$6 with amorphous	USPAT	2001/04/29 23:25
-	112	(dielectric and amorphous and crystal\$6) and capacitor	EPO; JPO; DERWENT; IBM TDB	2001/04/29 23:27
-	0	((dielectric and amorphous and crystal\$6) and capacitor) and crystalline adj silicon adj oxide	EPO; JPO; DERWENT; IBM TDB	2001/04/29 23:28
-	0	((("257/296-313") or ("257/532")).CCLS.) and crystalline adj silicon adj oxide with dielectric	EPO; JPO; DERWENT; IBM TDB	2001/04/29 23:28
-	0	((("257/296-313") or ("257/532")).CCLS.) and crystalline adj silicon adj oxide with dielectric	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/04/29 23:28
-	1	((("257/296-313") or ("257/532")).CCLS.) and crystalline adj silicon adj oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/04/29 23:29